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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	40MHz
Connectivity	UART/USART
Peripherals	Brown-out Detect/Reset, LVD, POR, PWM, WDT
Number of I/O	16
Program Memory Size	4KB (2K x 16)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	256 x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 5.5V
Data Converters	A/D 7x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	18-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic18lf1220-i-so

TABLE 1-2: PIC18F1220/1320 PINOUT I/O DESCRIPTIONS (CONTINUED)

	Pi	n Numb	er	Pin	Buffer	
Pin Name	PDIP/ SOIC	SSOP	QFN	Туре	Туре	Description
						PORTB is a bidirectional I/O port. PORTB can be software programmed for internal weak pull-ups on all inputs.
RB0/AN4/INT0 RB0 AN4 INT0	8	9	9	I/O I I	TTL Analog ST	Digital I/O. Analog input 4. External interrupt 0.
RB1/AN5/TX/CK/INT1 RB1 AN5 TX CK INT1	9	10	10	I/O I O I/O I	TTL Analog — ST ST	Digital I/O. Analog input 5. EUSART asynchronous transmit. EUSART synchronous clock (see related RX/DT). External interrupt 1.
RB2/P1B/INT2 RB2 P1B INT2	17	19	23	I/O O I	TTL — ST	Digital I/O. Enhanced CCP1/PWM output. External interrupt 2.
RB3/CCP1/P1A RB3 CCP1 P1A	18	20	24	I/O I/O O	TTL ST	Digital I/O. Capture 1 input/Compare 1 output/PWM 1 output. Enhanced CCP1/PWM output.
RB4/AN6/RX/DT/KBI0 RB4 AN6 RX DT KBI0	10	11	12	I/O /O	TTL Analog ST ST TTL	Digital I/O. Analog input 6. EUSART asynchronous receive. EUSART synchronous data (see related TX/CK). Interrupt-on-change pin.
RB5/PGM/KBI1 RB5 PGM KBI1	11	12	13	I/O I/O I	TTL ST TTL	Digital I/O. Low-Voltage ICSP™ Programming enable pin. Interrupt-on-change pin.
RB6/PGC/T1OSO/ T13CKI/P1C/KBI2 RB6 PGC T1OSO T13CKI P1C KBI2 RB7/PGD/T1OSI/ P1D/KBI3	12	13	15	I/O I/O O I	TTL ST — ST — TTL	Digital I/O. In-Circuit Debugger and ICSP programming clock pin. Timer1 oscillator output. Timer1/Timer3 external clock output. Enhanced CCP1/PWM output. Interrupt-on-change pin.
RB7 PGD T1OSI P1D KBI3				I/O I/O I O I	TTL ST CMOS — TTL	Digital I/O. In-Circuit Debugger and ICSP programming data pin. Timer1 oscillator input. Enhanced CCP1/PWM output. Interrupt-on-change pin.
Vss	5	5, 6	3, 5	Р		Ground reference for logic and I/O pins.
VDD	14	15, 16	17, 19	Р	_	Positive supply for logic and I/O pins.
NC	—	_	18	_	_	No connect.

Legend: TTL = TTL compatible input

ST = Schmitt Trigger input with CMOS levels

O = Output

OD = Open-drain (no P diode to VDD)

CMOS = CMOS compatible input or output

I = Input

P = Power

TABLE 2-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATOR

Osc Type	Crystal	Typical Capa Tes	
	Freq.	C1	C2
LP	32 kHz	33 pF	33 pF
	200 kHz	15 pF	15 pF
XT	1 MHz	33 pF	33 pF
	4 MHz	27 pF	27 pF
HS	4 MHz	27 pF	27 pF
	8 MHz	22 pF	22 pF
	20 MHz	15 pF	15 pF

Capacitor values are for design guidance only.

These capacitors were tested with the crystals listed below for basic start-up and operation. **These values are not optimized.**

Different capacitor values may be required to produce acceptable oscillator operation. The user should test the performance of the oscillator over the expected VDD and temperature range for the application.

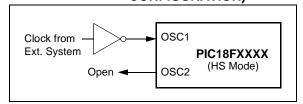
See the notes following this table for additional information.

Crystals Used:					
32 kHz	4 MHz				
200 kHz	8 MHz				
1 MHz	20 MHz				

- **Note 1:** Higher capacitance increases the stability of oscillator, but also increases the start-up time.
 - 2: When operating below 3V VDD, or when using certain ceramic resonators at any voltage, it may be necessary to use the HS mode or switch to a crystal oscillator.
 - 3: Since each resonator/crystal has its own characteristics, the user should consult the resonator/crystal manufacturer for appropriate values of external components.
 - **4:** Rs may be required to avoid overdriving crystals with low drive level specification.
 - **5:** Always verify oscillator performance over the VDD and temperature range that is expected for the application.

An external clock source may also be connected to the OSC1 pin in the HS mode, as shown in Figure 2-2.

FIGURE 2-2: EXTERNAL CLOCK INPUT OPERATION (HS OSC CONFIGURATION)



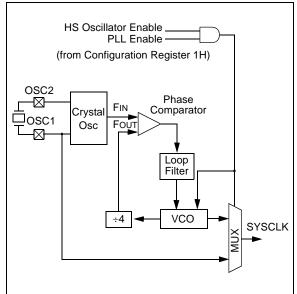
2.3 HSPLL

A Phase Locked Loop (PLL) circuit is provided as an option for users who wish to use a lower frequency crystal oscillator circuit, or to clock the device up to its highest rated frequency from a crystal oscillator. This may be useful for customers who are concerned with EMI due to high-frequency crystals.

The HSPLL mode makes use of the HS mode oscillator for frequencies up to 10 MHz. A PLL then multiplies the oscillator output frequency by 4 to produce an internal clock frequency up to 40 MHz.

The PLL is enabled only when the oscillator Configuration bits are programmed for HSPLL mode. If programmed for any other mode, the PLL is not enabled.

FIGURE 2-3: PLL BLOCK DIAGRAM



PIC18F1220/1320

3.6.1 EXAMPLE – EUSART

An adjustment may be indicated when the EUSART begins to generate framing errors, or receives data with errors while in Asynchronous mode. Framing errors indicate that the system clock frequency is too high – try decrementing the value in the OSCTUNE register to reduce the system clock frequency. Errors in data may suggest that the system clock speed is too low – increment OSCTUNE.

3.6.2 EXAMPLE - TIMERS

This technique compares system clock speed to some reference clock. Two timers may be used; one timer is clocked by the peripheral clock, while the other is clocked by a fixed reference source, such as the Timer1 oscillator.

Both timers are cleared, but the timer clocked by the reference generates interrupts. When an interrupt occurs, the internally clocked timer is read and both timers are cleared. If the internally clocked timer value is greater than expected, then the internal oscillator block is running too fast – decrement OSCTUNE.

3.6.3 EXAMPLE – CCP IN CAPTURE MODE

A CCP module can use free running Timer1 (or Timer3), clocked by the internal oscillator block and an external event with a known period (i.e., AC power frequency). The time of the first event is captured in the CCPRxH:CCPRxL registers and is recorded for use later. When the second event causes a capture, the time of the first event is subtracted from the time of the second event. Since the period of the external event is known, the time difference between events can be calculated.

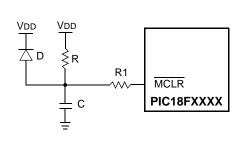
If the measured time is much greater than the calculated time, the internal oscillator block is running too fast – decrement OSCTUNE. If the measured time is much less than the calculated time, the internal oscillator block is running too slow–increment OSCTUNE.

4.1 Power-on Reset (POR)

A Power-on Reset pulse is generated on-chip when VDD rise is detected. To take advantage of the POR circuitry, just tie the $\overline{\text{MCLR}}$ pin through a resistor (1k to 10 k Ω) to VDD. This will eliminate external RC components usually needed to create a Power-on Reset delay. A minimum rise rate for VDD is specified (parameter D004). For a slow rise time, see Figure 4-2.

When the device starts normal operation (i.e., exits the Reset condition), device operating parameters (voltage, frequency, temperature, etc.) must be met to ensure operation. If these conditions are not met, the device must be held in Reset until the operating conditions are met.

FIGURE 4-2: EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP)



Note 1:External Power-on Reset circuit is required only if the VDD power-up slope is too slow. The diode D helps discharge the capacitor quickly when VDD powers down.

- 2: $R < 40 \text{ k}\Omega$ is recommended to make sure that the voltage drop across R does not violate the device's electrical specification.
- 3: $R1 \ge 1$ k Ω will limit any current flowing into \overline{MCLR} from external capacitor C, in the event of \overline{MCLR} /VPP pin breakdown due to Electrostatic Discharge (ESD) or Electrical Overstress (EOS).

4.2 Power-up Timer (PWRT)

The Power-up Timer (PWRT) of the PIC18F1220/1320 is an 11-bit counter, which uses the INTRC source as the clock input. This yields a count of 2048 x 32 μ s = 65.6 ms. While the PWRT is counting, the device is held in Reset.

The power-up time delay will vary from chip-to-chip due to VDD, temperature and process variation. See DC parameter 33 for details.

The PWRT is enabled by clearing Configuration bit, PWRTEN.

4.3 Oscillator Start-up Timer (OST)

The Oscillator Start-up Timer (OST) provides a 1024 oscillator cycle (from OSC1 input) delay after the PWRT delay is over (parameter 33). This ensures that the crystal oscillator or resonator has started and stabilized.

The OST time-out is invoked only for XT, LP, HS and HSPLL modes and only on Power-on Reset, or on exit from most low-power modes.

4.4 PLL Lock Time-out

With the PLL enabled in its PLL mode, the time-out sequence following a Power-on Reset is slightly different from other oscillator modes. A portion of the Power-up Timer is used to provide a fixed time-out that is sufficient for the PLL to lock to the main oscillator frequency. This PLL lock time-out (TPLL) is typically 2 ms and follows the Oscillator Start-up Time-out.

4.5 Brown-out Reset (BOR)

A Configuration bit, BOR, can disable (if clear/ programmed), or enable (if set) the Brown-out Reset circuitry. If VDD falls below VBOR (parameter D005) for greater than TBOR (parameter 35), the brown-out situation will reset the chip. A Reset may not occur if VDD falls below VBOR for less than TBOR. The chip will remain in Brown-out Reset until VDD rises above VBOR. If the Power-up Timer is enabled, it will be invoked after VDD rises above VBOR; it then will keep the chip in Reset for an additional time delay, TPWRT (parameter 33). If VDD drops below VBOR while the Power-up Timer is running, the chip will go back into a Brown-out Reset and the Power-up Timer will be initialized. Once VDD rises above VBOR, the Power-up Timer will execute the additional time delay. Enabling BOR Reset does not automatically enable the PWRT.

4.6 Time-out Sequence

On power-up, the time-out sequence is as follows: First, after the POR pulse has cleared, PWRT time-out is invoked (if enabled). Then, the OST is activated. The total time-out will vary based on oscillator configuration and the status of the PWRT. For example, in RC mode with the PWRT disabled, there will be no time-out at all. Figure 4-3, Figure 4-4, Figure 4-5, Figure 4-6 and Figure 4-7 depict time-out sequences on power-up.

Since the time-outs occur from the POR pulse, if MCLR is kept low long enough, all time-outs will expire. Bringing MCLR high will begin execution immediately (Figure 4-5). This is useful for testing purposes or to synchronize more than one PIC18FXXXX device operating in parallel.

Table 4-2 shows the Reset conditions for some Special Function Registers, while Table 4-3 shows the Reset conditions for all the registers.

TABLE 4-3: INITIALIZATION CONDITIONS FOR ALL REGISTERS (CONTINUED)

Register		Applicable Power-on Reset, Devices Brown-out Reset		MCLR Resets WDT Reset RESET Instruction Stack Resets	Wake-up via WDT or Interrupt
BSR	1220	1320	0000	0000	uuuu
INDF2	1220	1320	N/A	N/A	N/A
POSTINC2	1220	1320	N/A	N/A	N/A
POSTDEC2	1220	1320	N/A	N/A	N/A
PREINC2	1220	1320	N/A	N/A	N/A
PLUSW2	1220	1320	N/A	N/A	N/A
FSR2H	1220	1320	0000	0000	uuuu
FSR2L	1220	1320	xxxx xxxx	uuuu uuuu	uuuu uuuu
STATUS	1220	1320	x xxxx	u uuuu	u uuuu
TMR0H	1220	1320	0000 0000	0000 0000	uuuu uuuu
TMR0L	1220	1320	xxxx xxxx	uuuu uuuu	uuuu uuuu
T0CON	1220	1320	1111 1111	1111 1111	uuuu uuuu
OSCCON	1220	1320	0000 q000	0000 q000	uuuu qquu
LVDCON	1220	1320	00 0101	00 0101	uu uuuu
WDTCON	1220	1320	0	0	u
RCON ⁽⁴⁾	1220	1320	01 11q0	0q qquu	uu qquu
TMR1H	1220	1320	xxxx xxxx	uuuu uuuu	uuuu uuuu
TMR1L	1220	1320	xxxx xxxx	uuuu uuuu	uuuu uuuu
T1CON	1220	1320	0000 0000	u0uu uuuu	uuuu uuuu
TMR2	1220	1320	0000 0000	0000 0000	uuuu uuuu
PR2	1220	1320	1111 1111	1111 1111	1111 1111
T2CON	1220	1320	-000 0000	-000 0000	-uuu uuuu
ADRESH	1220	1320	xxxx xxxx	uuuu uuuu	uuuu uuuu
ADRESL	1220	1320	xxxx xxxx	uuuu uuuu	uuuu uuuu
ADCON0	1220	1320	00-0 0000	00-0 0000	uu-u uuuu
ADCON1	1220	1320	-000 0000	-000 0000	-uuu uuuu
ADCON2	1220	1320	0-00 0000	0-00 0000	u-uu uuuu
CCPR1H	1220	1320	xxxx xxxx	uuuu uuuu	uuuu uuuu
CCPR1L	1220	1320	xxxx xxxx	uuuu uuuu	uuuu uuuu
CCP1CON	1220	1320	0000 0000	0000 0000	uuuu uuuu
PWM1CON	1220	1320	0000 0000	0000 0000	uuuu uuuu
ECCPAS	1220	1320	0000 0000	0000 0000	uuuu uuuu

Legend: u = unchanged, x = unknown, - = unimplemented bit, read as '0', <math>q = value depends on condition. Shaded cells indicate conditions do not apply for the designated device.

- Note 1: One or more bits in the INTCONx or PIRx registers will be affected (to cause wake-up).
 - 2: When the wake-up is due to an interrupt and the GIEL or GIEH bit is set, the PC is loaded with the interrupt vector (0008h or 0018h).
 - **3:** When the wake-up is due to an interrupt and the GIEL or GIEH bit is set, the TOSU, TOSH and TOSL are updated with the current value of the PC. The STKPTR is modified to point to the next location in the hardware stack.
 - 4: See Table 4-2 for Reset value for specific condition.
 - 5: Bits 6 and 7 of PORTA, LATA and TRISA are enabled, depending on the Oscillator mode selected. When not enabled as PORTA pins, they are disabled and read '0'.
 - **6:** Bit 5 of PORTA is enabled if MCLR is disabled.

REGISTER 5-1: STKPTR: STACK POINTER REGISTER

R/C-0/0	R/C-0/0	U-0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0
STKFUL ⁽¹⁾	STKUNF ⁽¹⁾				SP<4:0>		
bit 7							bit 0

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	C = Clearable only bit

bit 7

STKFUL: Stack Full Flag bit⁽¹⁾

1 = Stack became full or overflowed

0 = Stack has not become full or overflowed

bit 6

STKUNF: Stack Underflow Flag bit⁽¹⁾

1 = Stack Underflow occurred

0 = Stack Underflow did not occur

bit 5

Unimplemented: Read as '0'

bit 4-0 **SP<4:0>:** Stack Pointer Location bits

Note 1: Bit 7 and bit 6 are cleared by user software or by a POR.

5.2.3 PUSH AND POP INSTRUCTIONS

Since the Top-of-Stack (TOS) is readable and writable, the ability to push values onto the stack and pull values off the stack, without disturbing normal program execution, is a desirable option. To push the current PC value onto the stack, a PUSH instruction can be executed. This will increment the Stack Pointer and load the current PC value onto the stack. TOSU, TOSH and TOSL can then be modified to place data or a return address on the stack.

The ability to pull the TOS value off of the stack and replace it with the value that was previously pushed onto the stack, without disturbing normal execution, is achieved by using the POP instruction. The POP instruction discards the current TOS by decrementing the Stack Pointer. The previous value pushed onto the stack then becomes the TOS value.

5.2.4 STACK FULL/UNDERFLOW RESETS

These Resets are enabled by programming the STVR bit in Configuration Register 4L. When the STVR bit is cleared, a full or underflow condition will set the appropriate STKFUL or STKUNF bit, but not cause a device Reset. When the STVR bit is set, a full or underflow condition will set the appropriate STKFUL or STKUNF bit and then cause a device Reset. The STKFUL or STKUNF bits are cleared by the user software or a Power-on Reset.

6.4 Erasing Flash Program Memory

The minimum erase block size is 32 words or 64 bytes under firmware control. Only through the use of an external programmer, or through ICSP control, can larger blocks of program memory be bulk erased. Word erase in Flash memory is not supported.

When initiating an erase sequence from the micro-controller itself, a block of 64 bytes of program memory is erased. The Most Significant 16 bits of the TBLPTR<21:6> point to the block being erased. TBLPTR<5:0> are ignored.

The EECON1 register commands the erase operation. The EEPGD bit must be set to point to the Flash program memory. The CFGS bit must be clear to access program Flash and data EEPROM memory. The WREN bit must be set to enable write operations. The FREE bit is set to select an erase operation. The WR bit is set as part of the required instruction sequence (as shown in Example 6-2) and starts the actual erase operation. It is not necessary to load the TABLAT register with any data as it is ignored.

For protection, the write initiate sequence using EECON2 must be used.

A long write is necessary for erasing the internal Flash. Instruction execution is halted while in a long write cycle. The long write will be terminated by the internal programming timer.

6.4.1 FLASH PROGRAM MEMORY ERASE SEQUENCE

The sequence of events for erasing a block of internal program memory location is:

- Load Table Pointer with address of row being erased.
- 2. Set the EECON1 register for the erase operation:
 - •set EEPGD bit to point to program memory;
 - clear the CFGS bit to access program memory;
 - •set WREN bit to enable writes;
 - •set FREE bit to enable the erase.
- 3. Disable interrupts.
- 4. Write 55h to EECON2.
- 5. Write AAh to EECON2.
- Set the WR bit. This will begin the row erase cycle.
- The CPU will stall for duration of the erase (about 2 ms using internal timer).
- 8. Execute a NOP.
- 9. Re-enable interrupts.

EXAMPLE 6-2: ERASING A FLASH PROGRAM MEMORY ROW

	MOVLW MOVWF MOVWF MOVLW MOVWF	CODE_ADDR_UPPER TBLPTRU CODE_ADDR_HIGH TBLPTRH CODE_ADDR_LOW TBLPTRL	; load TBLPTR with the base ; address of the memory block
ERASE_ROW			
	BSF BSF BSF BCF	EECON1, EEPGD EECON1, WREN EECON1, FREE INTCON, GIE	; point to FLASH program memory; enable write to memory; enable Row Erase operation; disable interrupts
Required Sequence	MOVLW MOVWF MOVWF BSF NOP	55h EECON2 AAh EECON2 EECON1, WR	<pre>; write 55H ; write AAH ; start erase (CPU stall)</pre>
	BSF	INTCON, GIE	; re-enable interrupts

EXAMPLE 6-3: WRITING TO FLASH PROGRAM MEMORY

```
MOVLW D'64
                                          ; number of bytes in erase block
          MOVWF
                 COUNTER
          MOVLW
                 BUFFER_ADDR_HIGH
                                         ; point to buffer
          MOVWF
                 FSR0H
          MOVLW
                 BUFFER_ADDR_LOW
          MOVWF FSR0L
                                      ; Load TBLPTR with the base
          MOVLW CODE_ADDR_UPPER
          MOVWF TBLPTRU
                                         ; address of the memory block
          MOVLW CODE_ADDR_HIGH
          MOVWF TBLPTRH
                                        ; 6 LSB = 0
          MOVLW CODE_ADDR_LOW
          MOVWF TBLPTRL
READ BLOCK
          TBLRD*+
                                         ; read into TABLAT, and inc
          MOVF TABLAT, W
                                         ; get data
          MOVWF POSTINCO
                                         ; store data and increment FSR0
          DECFSZ COUNTER
                                         ; done?
          GOTO READ_BLOCK
                                         ; repeat
MODIFY_WORD
          MOVLW DATA_ADDR_HIGH
                                        ; point to buffer
          MOVWF FSR0H
          MOVLW DATA_ADDR_LOW
          MOVWF
                 FSR0L
          MOVLW
                 NEW_DATA_LOW
                                         ; update buffer word and increment FSR0
          MOVWF
                 POSTINC0
          MOVLW NEW_DATA_HIGH
                                        ; update buffer word
          MOVWF INDF0
ERASE_BLOCK
          MOVLW CODE_ADDR_UPPER
                                        ; load TBLPTR with the base
                                         ; address of the memory block
          MOVWF TBLPTRU
          MOVLW CODE_ADDR_HIGH
          MOVWF
                 TBLPTRH
          MOVLW
                 CODE_ADDR_LOW
                                         ; 6 LSB = 0
          MOVWF
                 TBLPTRL
                 EECON1, CFGS
                                        ; point to PROG/EEPROM memory
          BCF
                 EECON1, EEPGD
                                        ; point to FLASH program memory
          BSF
                                    ; enable write to memory
; enable Row Erase operation
                 EECON1, WREN
               EECON1, FREE
          BSF
          BCF INTCON, GIE
                                   ; disable interrupts
          MOVLW 55h
                                        ; Required sequence
          MOVWF EECON2
                                         ; write 55H
          MOVLW
                 AAh
          MOVWF EECON2
                                         ; write AAH
                                          ; start erase (CPU stall)
          BSF
                 EECON1, WR
          NOP
               INTCON, GIE
          BSF
                                         ; re-enable interrupts
WRITE_BUFFER_BACK
          MOVLW 8
                                         ; number of write buffer groups of 8 bytes
          MOVWF COUNTER_HI
          MOVLW BUFFER_ADDR_HIGH
                                         ; point to buffer
          MOVWF
                 FSR0H
          MOVLW
                 BUFFER_ADDR_LOW
          MOVWF
                 FSR0L
PROGRAM_LOOP
          MOVLW 8
                                          ; number of bytes in holding register
          MOVWF COUNTER
```

REGISTER 7-1: EECON1: EEPROM CONTROL 1 REGISTER

R/W-x	R/W-x	U-0	R/W-0	R/W-x	R/W-0	R/S-0	R/S-0
EEPGD	CFGS	_	FREE	WRERR ⁽¹⁾	WREN	WR	RD
bit 7							bit 0

Legend:R = Readable bitW = Writable bitU = Unimplemented bit, read as '0'S = Bit can only be setx = Bit is unknown-n/n = Value at POR and BOR/Value at all other Resets'1' = Bit is set'0' = Bit is clearedHC = Bit is cleared by hardware

bit 7 **EEPGD:** Flash Program or Data EEPROM Memory Select bit

1 = Access program Flash memory0 = Access data EEPROM memory

bit 6 CFGS: Flash Program/Data EEPROM or Configuration Select bit

1 = Accesses Configuration, User ID and Device ID Registers

0 = Accesses Flash Program or data EEPROM Memory

bit 5 **Unimplemented:** Read as '0'

bit 4 FREE: Flash Row Erase Enable bit

1 = Erase the program memory row addressed by TBLPTR on the next WR command (cleared by completion of erase operation – TBLPTR<5:0> are ignored)

0 = Perform write only

bit 3 WRERR: EEPROM Error Flag bit⁽¹⁾

1 = A write operation was prematurely terminated (any Reset during self-timed programming)

0 = The write operation completed normally

bit 2 WREN: Program/Erase Enable bit

1 = Allows program/erase cycles

0 = Inhibits programming/erasing of program Flash and data EEPROM

bit 1 WR: Write Control bit

1 = Initiates a data EEPROM erase/write cycle or a program memory erase cycle or write cycle. (The operation is self-timed and the bit is cleared by hardware once write is complete. The WR bit can only be set (not cleared) in software.)

0 = Write cycle completed

bit 0 RD: Read Control bit

1 = Initiates a memory read (Read takes one cycle. RD is cleared in hardware. The RD bit can only be set (not cleared) in software. RD bit cannot be set when EEPGD = 1.)

0 = Read completed

Note 1: When a WRERR occurs, the EEPGD and CFGS bits are not cleared. This allows tracing of the error condition.

REGISTER 9-7: PIE2: PERIPHERAL INTERRUPT ENABLE REGISTER 2

R/W-0/0	U-0	U-0	R/W-0/0	U-0	R/W-0/0	R/W-0/0	U-0
OSCFIE	_	_	EEIE	_	LVDIE	TMR3IE	_
bit 7							bit 0

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

u = Bit is unchanged x = Bit is unknown -n/n = Value at POR and BOR/Value at all other Resets

'1' = Bit is set '0' = Bit is cleared

bit 7 OSCFIE: Oscillator Fail Interrupt Enable bit

1 = Enabled
0 = Disabled

bit 6-5 **Unimplemented:** Read as '0'

bit 4 **EEIE:** Data EEPROM/Flash Write Operation Interrupt Enable bit

1 =Enabled 0 =Disabled

bit 3 Unimplemented: Read as '0'

bit 2 LVDIE: Low-Voltage Detect Interrupt Enable bit

1 =Enabled 0 =Disabled

bit 1 TMR3IE: TMR3 Overflow Interrupt Enable bit

1 =Enabled 0 =Disabled

bit 0 **Unimplemented:** Read as '0'

9.4 IPR Registers

The IPR registers contain the individual priority bits for the peripheral interrupts. Due to the number of peripheral interrupt sources, there are two Peripheral Interrupt Priority registers (IPR1, IPR2). Using the priority bits requires that the Interrupt Priority Enable (IPEN) bit be set.

REGISTER 9-8: IPR1: PERIPHERAL INTERRUPT PRIORITY REGISTER 1

U-0	R/W-1/1	R/W-1/1	R/W-1/1	U-0	R/W-1/1	R/W-1/1	R/W-1/1
_	ADIP	RCIP	TXIP	_	CCP1IP	TMR2IP	TMR1IP
bit 7							bit 0

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

bit 7	Unimplemented: Read as '0'
bit 6	ADIP: A/D Converter Interrupt Priority bit
	1 = High priority
	0 = Low priority
bit 5	RCIP: EUSART Receive Interrupt Priority bit
	1 = High priority
	0 = Low priority
bit 4	TXIP: EUSART Transmit Interrupt Priority bit
	1 = High priority
	0 = Low priority
bit 3	Unimplemented: Read as '0'
bit 2	CCP1IP: CCP1 Interrupt Priority bit
	1 = High priority
	0 = Low priority
bit 1	TMR2IP: TMR2 to PR2 Match Interrupt Priority bit
	1 = High priority
	0 = Low priority
bit 0	TMR1IP: TMR1 Overflow Interrupt Priority bit
	1 = High priority
	0 = Low priority

9.6 INTn Pin Interrupts

External interrupts on the RB0/INT0, RB1/INT1 and RB2/INT2 pins are edge-triggered: either rising if the corresponding INTEDGx bit is set in the INTCON2 register, or falling if the INTEDGx bit is clear. When a valid edge appears on the RBx/INTx pin, the corresponding flag bit, INTxF, is set. This interrupt can be disabled by clearing the corresponding enable bit, INTxE. Flag bit, INTxF, must be cleared in software in the Interrupt Service Routine before re-enabling the interrupt. All external interrupts (INT0, INT1 and INT2) can wake-up the processor from low-power modes. If the Global Interrupt Enable bit, GIE, is set, the processor will branch to the interrupt vector following wake-up.

Interrupt priority for INT1 and INT2 is determined by the value contained in the interrupt priority bits, INT1IP (INTCON3<6>) and INT2IP (INTCON3<7>). There is no priority bit associated with INT0. It is always a high priority interrupt source.

9.7 TMR0 Interrupt

In 8-bit mode (which is the default), an overflow (FFh \rightarrow 00h) in the TMR0 register will set flag bit, TMR0IF. In 16-bit mode, an overflow (FFFh \rightarrow 0000h) in the TMR0H:TMR0L registers will set flag bit, TMR0IF. The interrupt can be enabled/disabled by setting/clearing enable bit, TMR0IE (INTCON<5>). Interrupt priority for Timer0 is determined by the value contained in the interrupt priority bit, TMR0IP (INTCON2<2>). See **Section 11.0 "Timer0 Module"** for further details on the Timer0 module.

9.8 PORTB Interrupt-on-Change

An input change on PORTB</ri>
7:4> sets flag bit, RBIF (INTCON<0>). The interrupt can be enabled/disabled by setting/clearing enable bit, RBIE (INTCON<3>). Interrupt priority for PORTB interrupt-on-change is determined by the value contained in the interrupt priority bit, RBIP (INTCON2<0>).

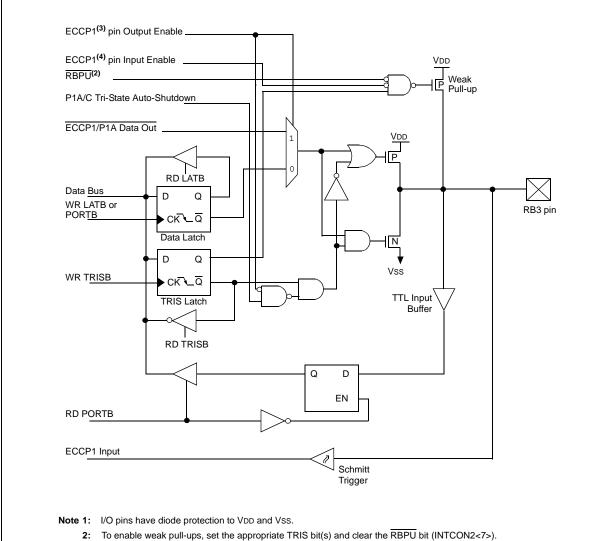
9.9 Context Saving During Interrupts

During interrupts, the return PC address is saved on the stack. Additionally, the WREG, Status and BSR registers are saved on the fast return stack. If a fast return from interrupt is not used (see **Section 5.3 "Fast Register Stack"**), the user may need to save the WREG, Status and BSR registers on entry to the Interrupt Service Routine. Depending on the user's application, other registers may also need to be saved. Example 9-1 saves and restores the WREG, Status and BSR registers during an Interrupt Service Routine.

EXAMPLE 9-1: SAVING STATUS, WREG AND BSR REGISTERS IN RAM

```
MOVWF
       W TEMP
                                   ; W_TEMP is in virtual bank
MOVFF
       STATUS, STATUS_TEMP
                                   ; STATUS_TEMP located anywhere
MOVFF
       BSR, BSR_TEMP
                                   ; BSR_TMEP located anywhere
; USER ISR CODE
MOVFF
       BSR_TEMP, BSR
                                   ; Restore BSR
MOVE
       W_TEMP, W
                                   ; Restore WREG
MOVFF
       STATUS_TEMP, STATUS
                                   ; Restore STATUS
```

FIGURE 10-10: **BLOCK DIAGRAM OF RB3/CCP1/P1A PIN**



- 3: ECCP1 pin output enable active for any PWM mode and Compare mode, where CCP1M<3:0> = 1000 or 1001.
- 4: ECCP1 pin input enable active for Capture mode only.

15.3.4 CCP PRESCALER

There are four prescaler settings, specified by bits CCP1M3:CCP1M0. Whenever the CCP module is turned off or the CCP module is not in Capture mode, the prescaler counter is cleared. This means that any Reset will clear the prescaler counter.

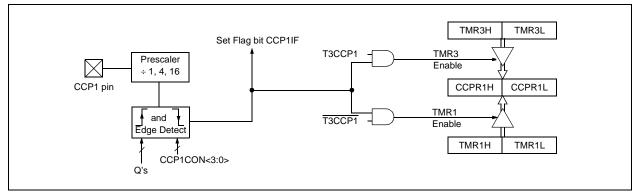
Switching from one capture prescaler to another may generate an interrupt. Also, the prescaler counter will not be cleared; therefore, the first capture may be from a non-zero prescaler. Example 15-1 shows the

recommended method for switching between capture prescalers. This example also clears the prescaler counter and will not generate the "false" interrupt.

EXAMPLE 15-1: CHANGING BETWEEN CAPTURE PRESCALERS

CLRF	CCP1CON	; Turn CCP module off
MOVLW	NEW_CAPT_PS	; Load WREG with the
		; new prescaler mode
		; value and CCP ON
MOVWF	CCP1CON	; Load CCP1CON with
		; this value

FIGURE 15-1: CAPTURE MODE OPERATION BLOCK DIAGRAM



15.4 Compare Mode

In Compare mode, the 16-bit CCPR1 register value is constantly compared against either the TMR1 register pair value, or the TMR3 register pair value. When a match occurs, the RB3/CCP1/P1A pin:

- · Is driven high
- · Is driven low
- Toggles output (high-to-low or low-to-high)
- · Remains unchanged (interrupt only)

The action on the pin is based on the value of control bits, CCP1M3:CCP1M0. At the same time, interrupt flag bit, CCP1IF, is set.

15.4.1 CCP PIN CONFIGURATION

The user must configure the RB3/CCP1/P1A pin as an output by clearing the TRISB<3> bit.

Note: Clearing the CCP1CON register will force the RB3/CCP1/P1A compare output latch to the default low level. This is not the PORTB I/O data latch.

15.4.2 TIMER1/TIMER3 MODE SELECTION

Timer1 and/or Timer3 must be running in Timer mode or Synchronized Counter mode if the CCP module is using the compare feature. In Asynchronous Counter mode, the compare operation may not work.

15.4.3 SOFTWARE INTERRUPT MODE

When generate software interrupt is chosen, the RB3/CCP1/P1A pin is not affected. CCP1IF is set and an interrupt is generated (if enabled).

15.4.4 SPECIAL EVENT TRIGGER

In this mode, an internal hardware trigger is generated, which may be used to initiate an action.

The special event trigger output of CCP1 resets the TMR1 register pair. This allows the CCPR1 register to effectively be a 16-bit programmable period register for Timer1.

The special event trigger also sets the GO/DONE bit (ADCON0<1>). This starts a conversion of the currently selected A/D channel if the A/D is on.

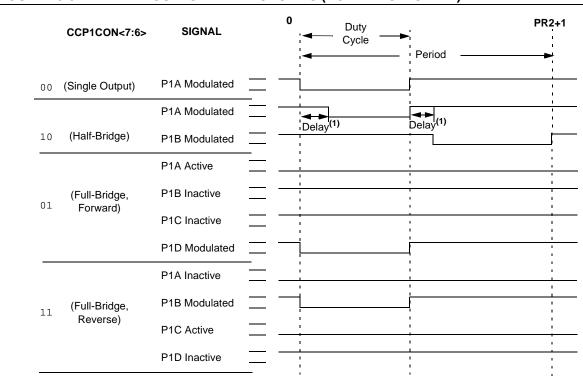


FIGURE 15-5: PWM OUTPUT RELATIONSHIPS (ACTIVE-LOW STATE)

Relationships:

- Period = 4 * Tosc * (PR2 + 1) * (TMR2 Prescale Value)
- Duty Cycle = Tosc * (CCPR1L<7:0>:CCP1CON<5:4>) * (TMR2 Prescale Value)
- Delay = 4 * Tosc * (PWM1CON<6:0>)

Note 1: Dead-band delay is programmed using the PWM1CON register (Section 15.5.6 "Programmable Dead-Band Delay").

IORLW Inclusive OR literal with W

Syntax: [label] IORLW k

 $\label{eq:constraints} \begin{array}{ll} \text{Operands:} & 0 \leq k \leq 255 \\ \\ \text{Operation:} & (W) .OR. \ k \rightarrow W \end{array}$

Status Affected: N, Z

Encoding: 0000 1001 kkkk kkkk

Description: The contents of W are OR'ed with

the 8-bit literal 'k'. The result is

placed in W.

Words: 1 Cycles: 1

Q Cycle Activity:

Q1	Q2	Q3	Q4
Decode	Read	Process	Write to W
	literal 'k'	Data	

Example: IORLW 0x35

Before Instruction

W = 0x9A

After Instruction

W = 0xBF

IOR	WF	Inclusive	Inclusive OR W with f		
Synt	ax:	[label]	IORWF	f [,c	d [,a]]
Ope	rands:	$0 \le f \le 258$ $d \in [0,1]$ $a \in [0,1]$	5		
Ope	ration:	(W) .OR.	$(f) \rightarrow de$	st	
Statu	us Affected:	N, Z			
Enco	oding:	0001	00da	fff	f ffff
Desc	cription:	Inclusive OR W with register 'f'. 'd' is '0', the result is placed in W 'd' is '1', the result is placed back register 'f' (default). If 'a' is '0', th Access Bank will be selected, ov riding the BSR value. If 'a' = 1, th the bank will be selected as per t BSR value (default).		ced in W. If ced back in ' is '0', the ected, over- fa' = 1, then	
Wor	ds:	1			
Cycles:		1			
Q Cycle Activity:					
	Q1	Q2	Q3	3	Q4
	Decode	Read	Proce	ess	Write to

Example: IORWF RESULT, W

register 'f'

Data

destination

Before Instruction

RESULT = 0x13 W = 0x91

After Instruction

RESULT = 0x13 W = 0x93

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MOVLW		Move lite	eral to W	,		
Synt	ax:	[label]	MOVLW	/ k		
Ope	rands:	$0 \le k \le 2$	55			
Ope	ration:	$k\toW$				
Statu	us Affected:	None				
Enco	oding:	0000	1110	kkŀ	k	kkkk
Desc	cription:	The 8-bit into W.	literal 'k'	is lo	adeo	i
Wor	ds:	1				
Cycles:		1				
QC	cycle Activity:					
	Q1	Q2	Q3	3		Q4
	Decode	Read	Proce	ess	ıW	ite to W

Example: MOVLW 0x5A

literal 'k'

After Instruction

W = 0x5A

MOV	/WF	Move W t	o f			
Synt	tax:	[label]	MOVWI	- f [,a	a]	
Ope	rands:	$0 \le f \le 255$ $a \in [0,1]$	5			
Ope	ration:	$(W) \rightarrow f$				
Stati	us Affected:	None				
Ence	oding:	0110	111a	ffff	ffff	
Des	cription:	256-byte be Access Bariding the	f' can be bank. If ank will BSR val will be se	e anywh fa' is '0' be sele lue. If fa elected	nere in the	
Wor	ds:	1				
Cycl	es:	1	1			
Q C	Cycle Activity:					
	Q1	Q2	Q3	3	Q4	
	Decode	Read register 'f'	Proce Dat		Write register 'f'	

Example: MOVWF REG

Before Instruction

W = 0x4F REG = 0xFF

After Instruction

W = 0x4F REG = 0x4F

SLEEP Enter Sleep mode

Syntax: [label] SLEEP

Operands: None

Operation: $00h \rightarrow WDT$,

 $0 \rightarrow WDT$ postscaler,

 $1 \to \overline{TO}, \\ 0 \to \overline{PD}$

Status Affected: TO. PD

Encoding: 0000 0000 0000 0011

Description: The Power-down Status bit (PD)

is cleared. The Time-out status bit (TO) is set. The Watchdog Timer and its postscaler are cleared. The processor is put into Sleep mode with the oscillator stopped.

1

Q Cycle Activity:

Words:

Cycles:

_	Q1	Q2	Q3	Q4
	Decode	No	Process	Go to
		operation	Data	Sleep

Example: SLEEP

Before Instruction

 $\frac{\overline{\text{TO}}}{\text{PD}} = ?$

After Instruction

 $\overline{\frac{\text{TO}}{\text{PD}}} = \frac{1}{0}$

† If WDT causes wake-up, this bit is cleared.

SUBFWB Subtract f from W with borrow

Syntax: [label] SUBFWB f [,d [,a]]

Operands: $0 \le f \le 255$

 $d \in [0,1]$ $a \in [0,1]$

Operation: $(W) - (f) - (\overline{C}) \rightarrow dest$

Status Affected: N, OV, C, DC, Z

Encoding: 0101 01da ffff ffff

Description: Subtract register 'f' and Carry flag

(borrow) from W (2's complement method). If 'd' is '0', the result is stored in W. If 'd' is '1', the result is stored in register 'f' (default). If 'a' is '0', the Access Bank will be selected, overriding the BSR value.

If 'a' is '1', then the bank will be selected as per the BSR value

(default).

Words: 1 Cycles: 1

Q Cycle Activity:

Q1	Q2	Q3	Q4
Decode	Read	Process	Write to
	register 'f'	Data	destination

Example 1: SUBFWB REG

Before Instruction

REG = 0x03 W = 0x02 C = 0x01

After Instruction

REG = 0xFF W = 0x02 C = 0x00 Z = 0x00

N = 0x01; result is negative

Example 2: SUBFWB REG, 0, 0

Before Instruction REG =

REG = 2 W = 5 C = 1

After Instruction

REG = 2 W = 3 C = 1 Z = 0 N = 0

; result is positive

Example 3: SUBFWB REG, 1, 0

Before Instruction

REG = 1 W = 2 C = 0

After Instruction

REG = 0 W = 2

C = 1 Z = 1

; result is zero

XORWF Exclusive OR W with f

Syntax: [label] XORWF f [,d [,a]]

Operands: $0 \le f \le 255$

 $\begin{array}{l} d \in [0,1] \\ a \in [0,1] \end{array}$

Operation: (W) .XOR. (f) \rightarrow dest

Status Affected: N, Z

Encoding: 0001 10da ffff ffff

Description: Exclusive OR the contents of W

with register 'f'. If 'd' is '0', the result is stored in W. If 'd' is '1', the result is stored back in the register 'f' (default). If 'a' is '0', the Access Bank will be selected, overriding the BSR value. If 'a' is '1', then the bank will be selected as per the

BSR value (default).

Words: 1 Cycles: 1

Q Cycle Activity:

Q1	Q2	Q3	Q4
Decode	Read	Process	Write to
	register 'f'	Data	destination

Example: XORWF REG

Before Instruction

REG = 0xAF W = 0xB5

After Instruction

 $\begin{array}{ccc} \mathsf{REG} & = & \mathsf{0x1A} \\ \mathsf{W} & = & \mathsf{0xB5} \end{array}$

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APPENDIX E: MIGRATION FROM MID-RANGE TO ENHANCED DEVICES

A detailed discussion of the differences between the mid-range MCU devices (i.e., PIC16CXXX) and the enhanced devices (i.e., PIC18FXXX) is provided in AN716, "Migrating Designs from PIC16C74A/74B to PIC18C442". The changes discussed, while device specific, are generally applicable to all mid-range to enhanced device migrations.

This Application Note is available as Literature Number DS00716.

APPENDIX F: MIGRATION FROM HIGH-END TO ENHANCED DEVICES

A detailed discussion of the migration pathway and differences between the high-end MCU devices (i.e., PIC17CXXX) and the enhanced devices (i.e., PIC18FXXX) is provided in AN726, "PIC17CXXX to PIC18CXXX Migration".

This Application Note is available as Literature Number DS00726.